

# 74AUP2G97DPJ Datasheet



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DiGi Electronics Part Number 74AUP2G97DPJ-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number 74AUP2G97DPJ

Description IC GATE DUAL PCB MULTI 10TSSOP

**Detailed Description** Configurable Multiple Function Configurable 2 Circ

uit 3 Input 10-TSSOP



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## **Purchase and inquiry**

| Manufacturer Product Number:                   | Manufacturer:  |
|--|--|
| 74AUP2G97DPJ                                   | Nexperia USA Inc.                                    |
| Series:  | Product Status:                                      |
| 74AUP  | Active   |
| Logic Type:                                    | Number of Circuits:                                  |
| Configurable Multiple Function                 | 2  |
| Number of Inputs:                              | Schmitt Trigger Input:                               |
| 3  | Yes  |
| Output Type:                                   | Current - Output High, Low:                          |
|  |  |
| Single-Ended                                   | 4mA, 4mA   |
| Single-Ended  Voltage - Supply:                | 4mA, 4mA Operating Temperature:                      |
|  |  |
| Voltage - Supply:                              | Operating Temperature:                               |
| Voltage - Supply:<br>0.8V ~ 3.6V               | Operating Temperature: -40°C ~ 125°C                 |
| Voltage - Supply:  0.8V ~ 3.6V  Mounting Type: | Operating Temperature: -40°C ~ 125°C Package / Case: |

## **Environmental & Export classification**

8542.39.0001

| RoHS Status:     | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant  | 1 (Unlimited)                     |
| REACH Status:    | ECCN:                             |
| REACH Unaffected | EAR99                             |
| HTSUS:           |                                   |

## **74AUP2G97**

## Low-power dual PCB configurable multiple function gate Rev. 4 — 1 August 2023 Product data sheet

## 1. General description

The 74AUP2G97 is a dual configurable multiple function gate with Schmitt-trigger inputs. Each gate within the device can be configured as any of the following logic functions MUX, AND, OR, NAND, NOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to  $V_{CC}$  or GND.

This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

#### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial power-down mode operation
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

## 3. Ordering information

#### **Table 1. Ordering information**

| Type number | Package           |         |   |           |  |  |  |  |
|-------------|-------------------|---------|---|-----------|--|--|--|--|
|             | Temperature range | Name    | Description   | Version   |  |  |  |  |
| 74AUP2G97DP | -40 °C to +125 °C | TSSOP10 | plastic thin shrink small outline package; 10 leads; body width 3 mm                          | SOT552-1  |  |  |  |  |
| 74AUP2G97GU | -40 °C to +125 °C | XQFN10  | plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.40 × 1.80 × 0.50 mm | SOT1160-1 |  |  |  |  |

## 4. Marking

#### Table 2. Marking

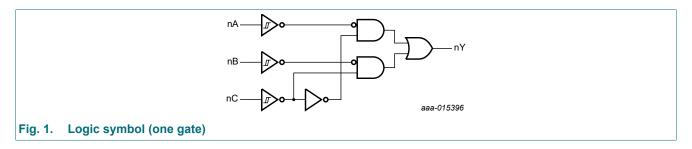
| Type number | Marking code [1] |
|-------------|------------------|
| 74AUP2G97DP | aV               |
| 74AUP2G97GU | aV               |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.



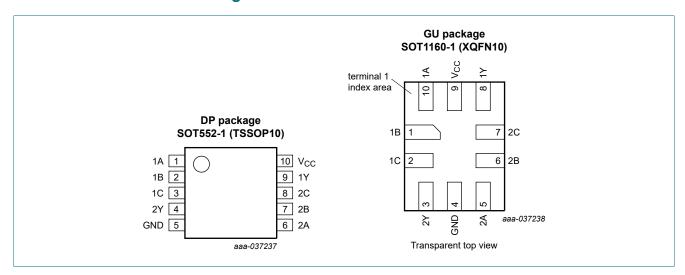
#### Low-power dual PCB configurable multiple function gate

## 5. Functional diagram



## 6. Pinning information

#### 6.1. Pinning



#### 6.2. Pin description

Table 3. Pin description

| Symbol          | Pin      | Description |                |
|-----------------|----------|-------------|----------------|
|                 | SOT552-1 | SOT1160-1   |                |
| 1A, 2A          | 1, 6     | 10, 5       | data input     |
| 1B, 2B          | 7 1, 6   |             | data input     |
| 1C, 2C          | 3, 8     | 2, 7        | data input     |
| 1Y, 2Y          | 9, 4     | 8, 3        | data output    |
| GND             | 5        | 4           | ground (0 V)   |
| V <sub>CC</sub> | 10       | 9           | supply voltage |

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#### Low-power dual PCB configurable multiple function gate

## 7. Functional description

#### **Table 4. Function table**

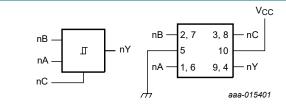
 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

| Input |    |    | Output |
|-------|----|----|--------|
| nC    | nB | nA | nY     |
| L     | L  | L  | L      |
| L     | L  | Н  | L      |
| L     | Н  | L  | Н      |
| L     | Н  | Н  | Н      |
| Н     | L  | L  | L      |
| Н     | L  | Н  | Н      |
| Н     | Н  | L  | L      |
| Н     | Н  | Н  | Н      |

## 7.1. Logic configurations

Table 5. Function selection table

| Logic function                       | Figure     |  |  |  |
|--------------------------------------|------------|--|--|--|
| 2-input MUX                          | see Fig. 2 |  |  |  |
| 2-input AND                          | see Fig. 3 |  |  |  |
| 2-input OR with one input inverted   | see Fig. 4 |  |  |  |
| 2-input NAND with one input inverted | see Fig. 4 |  |  |  |
| 2-input AND with one input inverted  | see Fig. 5 |  |  |  |
| 2-input NOR with one input inverted  | see Fig. 5 |  |  |  |
| 2-input OR                           | see Fig. 6 |  |  |  |
| Inverter                             | see Fig. 7 |  |  |  |
| Buffer                               | see Fig. 8 |  |  |  |



Pin numbers are not valid for SOT1160-1 package

NA — II — nY — nY — 1, 6 9, 4 — nY — aaa-015402

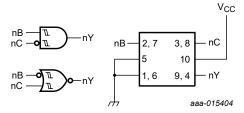
2-input AND gate

Pin numbers are not valid for SOT1160-1 package

Fig. 2. 2-input MUX

Pin numbers are not valid for SOT1160-1 package

Fig. 4. 2-input NAND gate with input A inverted or 2-input OR gate with input C inverted



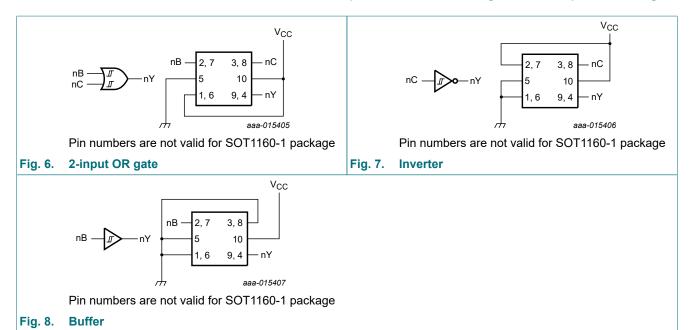
Pin numbers are not valid for SOT1160-1 package

Fig. 5. 2-input NOR gate with input B inverted or 2-input AND gate with input C inverted

Fig. 3.

aaa-015403

#### Low-power dual PCB configurable multiple function gate



## 8. Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions   | Min  | Max  | Unit |
|------------------|-------------------------|--|------|------|------|
| $V_{CC}$         | supply voltage          |  | -0.5 | +4.6 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < 0 V   | -50  | -    | mA   |
| VI               | input voltage           | [1]  | -0.5 | +4.6 | V    |
| I <sub>OK</sub>  | output clamping current | V <sub>O</sub> < 0 V   | -50  | -    | mA   |
| Vo               | output voltage          | Active mode and Power-down mode [1]                            | -0.5 | +4.6 | V    |
| Io               | output current          | $V_O = 0 V \text{ to } V_{CC}$                                 | -    | ±20  | mA   |
| I <sub>CC</sub>  | supply current          |  | -    | 50   | mA   |
| $I_{GND}$        | ground current          |  | -50  | -    | mA   |
| T <sub>stg</sub> | storage temperature     |  | -65  | +150 | °C   |
| P <sub>tot</sub> | total power dissipation | $T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [2] | -    | 250  | mW   |

<sup>1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 9. Recommended operating conditions

Table 7. Recommended operating conditions

| Tuble 1. Necommended operating conditions |                     |  |     |                 |      |  |
|---|---------------------|--|-----|-----------------|------|--|
| Symbol                                    | Parameter           | Conditions                             | Min | Max             | Unit |  |
| V <sub>CC</sub>                           | supply voltage      |  | 0.8 | 3.6             | V    |  |
| VI  | input voltage       |  | 0   | 3.6             | V    |  |
| Vo  | output voltage      | Active mode                            | 0   | V <sub>CC</sub> | V    |  |
|   |                     | Power-down mode; V <sub>CC</sub> = 0 V | 0   | 3.6             | V    |  |
| T <sub>amb</sub>                          | ambient temperature |  | -40 | +125            | °C   |  |

<sup>[2]</sup> For SOT552-1 (TSSOP10) packages: P<sub>tot</sub> derates linearly with 8.3 mW/K above 120 °C. For SOT1160-1 (XQFN10) package: P<sub>tot</sub> derates linearly with 7.1 mW/K above 115 °C.

#### Low-power dual PCB configurable multiple function gate

## 10. Static characteristics

#### **Table 8. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol               | Parameter                            | Conditions  | Min                    | Тур | Max                   | Unit |
|----------------------|--------------------------------------|---|------------------------|-----|-----------------------|------|
| T <sub>amb</sub> = 2 | 25 °C                                |   |                        |     |                       |      |
| V <sub>OH</sub>      | HIGH-level output voltage            | $V_I = V_{T+}$ or $V_{T-}$  |                        |     |                       |      |
|                      |                                      | $I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 $V$ to 3.6 $V$                          | V <sub>CC</sub> - 0.1  | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                             | 0.75 × V <sub>CC</sub> | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                             | 1.11                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                            | 1.32                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                             | 2.05                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                             | 1.9                    | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                             | 2.72                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                             | 2.6                    | -   | -                     | V    |
| V <sub>OL</sub>      | LOW-level output voltage             | $V_I = V_{T+}$ or $V_{T-}$  |                        |     |                       |      |
|                      |                                      | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V                      | -                      | -   | 0.1                   | V    |
|                      |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                              | -                      | -   | 0.3 × V <sub>CC</sub> | V    |
|                      |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                              | -                      | -   | 0.31                  | V    |
|                      |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                             | -                      | -   | 0.31                  | V    |
|                      |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                              | -                      | -   | 0.31                  | V    |
|                      |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                              | -                      | -   | 0.44                  | V    |
|                      |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                              | -                      | -   | 0.31                  | V    |
|                      |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                              | -                      | -   | 0.44                  | V    |
| l <sub>l</sub>       | input leakage current                | $V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V                               | -                      | -   | ±0.1                  | μΑ   |
| l <sub>OFF</sub>     | power-off leakage current            | $V_1$ or $V_0 = 0 V$ to 3.6 V; $V_{CC} = 0 V$                                 | -                      | -   | ±0.2                  | μΑ   |
| Δl <sub>OFF</sub>    | additional power-off leakage current | $V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V                        | -                      | -   | ±0.2                  | μΑ   |
| I <sub>CC</sub>      | supply current                       | $V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A;<br>$V_{CC}$ = 0.8 V to 3.6 V           | -                      | -   | 0.5                   | μΑ   |
| ΔI <sub>CC</sub>     | additional supply current            | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1] | -                      | -   | 40                    | μΑ   |
| Cı                   | input capacitance                    | $V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$                              | -                      | 1.1 | -                     | pF   |
| Co                   | output capacitance                   | $V_O = GND; V_{CC} = 0 V$   | -                      | 1.7 | -                     | pF   |
| T <sub>amb</sub> = - | 40 °C to +85 °C                      |   |                        |     |                       |      |
| V <sub>OH</sub>      | HIGH-level output voltage            | $V_I = V_{T+}$ or $V_{T-}$  |                        |     |                       |      |
|                      |                                      | $I_{O}$ = -20 µA; $V_{CC}$ = 0.8 V to 3.6 V                                   | V <sub>CC</sub> - 0.1  | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                             | 0.7 × V <sub>CC</sub>  | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                             | 1.03                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                            | 1.30                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                             | 1.97                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                             | 1.85                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                             | 2.67                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                             | 2.55                   | -   | -                     | V    |

#### Low-power dual PCB configurable multiple function gate

| Symbol                | Parameter                               | Conditions  | Min                    | Тур | Max                    | Unit |
|-----------------------|---|---|------------------------|-----|------------------------|------|
| V <sub>OL</sub>       | LOW-level output voltage                | $V_I = V_{T+}$ or $V_{T-}$  |                        |     |                        |      |
|                       |   | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V                      | -                      | -   | 0.1                    | V    |
|                       |   | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                              | -                      | -   | 0.3 × V <sub>CC</sub>  | V    |
|                       |   | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                              | -                      | -   | 0.37                   | V    |
|                       |   | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                             | -                      | -   | 0.35                   | V    |
|                       |   | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                              | -                      | -   | 0.33                   | V    |
|                       |   | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                              | -                      | -   | 0.45                   | V    |
|                       |   | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                              | -                      | -   | 0.33                   | V    |
|                       |   | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                              | -                      | -   | 0.45                   | V    |
| l <sub>l</sub>        | input leakage current                   | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                 | -                      | -   | ±0.5                   | μA   |
| I <sub>OFF</sub>      | power-off leakage current               | $V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V                             | -                      | -   | ±0.5                   | μA   |
| Δl <sub>OFF</sub>     | additional power-off<br>leakage current | $V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V to 0.2 V                    | -                      | -   | ±0.6                   | μΑ   |
| I <sub>CC</sub>       | supply current                          | $V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V              | -                      | -   | 0.9                    | μΑ   |
| $\Delta I_{CC}$       | additional supply current               | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1] | -                      | -   | 50                     | μΑ   |
| T <sub>amb</sub> = -4 | 10 °C to +125 °C                        |   |                        |     |                        |      |
| V <sub>OH</sub>       | HIGH-level output voltage               | $V_I = V_{T+}$ or $V_{T-}$  |                        |     |                        |      |
|                       |   | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V                     | V <sub>CC</sub> - 0.11 | -   | -                      | V    |
|                       |   | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                             | 0.6 × V <sub>CC</sub>  | -   | -                      | V    |
|                       |   | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                             | 0.93                   | -   | -                      | V    |
|                       |   | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                            | 1.17                   | -   | -                      | V    |
|                       |   | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                             | 1.77                   | -   | -                      | V    |
|                       |   | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                             | 1.67                   | -   | -                      | V    |
|                       |   | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                             | 2.40                   | -   | -                      | V    |
|                       |   | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                             | 2.30                   | -   | -                      | V    |
| V <sub>OL</sub>       | LOW-level output voltage                | $V_I = V_{T+}$ or $V_{T-}$  |                        |     |                        |      |
|                       |   | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V                      | -                      | -   | 0.11                   | V    |
|                       |   | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                              | -                      | -   | 0.33 × V <sub>CC</sub> | V    |
|                       |   | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                              | -                      | -   | 0.41                   | V    |
|                       |   | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                             | -                      | -   | 0.39                   | V    |
|                       |   | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                              | -                      | -   | 0.36                   | V    |
|                       |   | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                              | -                      | -   | 0.50                   | V    |
|                       |   | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                              | -                      | -   | 0.36                   | V    |
|                       |   | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                              | -                      | -   | 0.50                   | V    |
| I <sub>I</sub>        | input leakage current                   | $V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V                               | -                      | -   | ±0.75                  | μA   |
| I <sub>OFF</sub>      | power-off leakage current               | $V_{I}$ or $V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$      | -                      | -   | ±0.75                  | μA   |
| ΔI <sub>OFF</sub>     | additional power-off<br>leakage current | $V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V to 0.2 V                    | -                      | -   | ±0.75                  | μΑ   |
| I <sub>CC</sub>       | supply current                          | $V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A;<br>$V_{CC}$ = 0.8 V to 3.6 V           | -                      | -   | 1.4                    | μA   |
| Δl <sub>CC</sub>      | additional supply current               | $V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1] | -                      | -   | 75                     | μA   |

<sup>[1]</sup> One input at  $V_{CC}$  - 0.6 V, other input at  $V_{CC}$  or GND.

#### Low-power dual PCB configurable multiple function gate

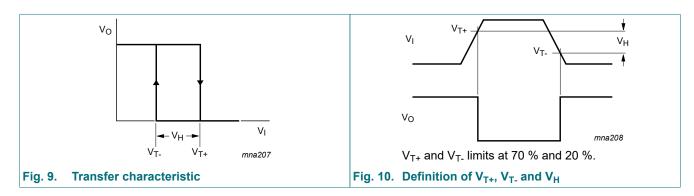
#### 10.1. Transfer characteristics

**Table 9. Transfer characteristics** 

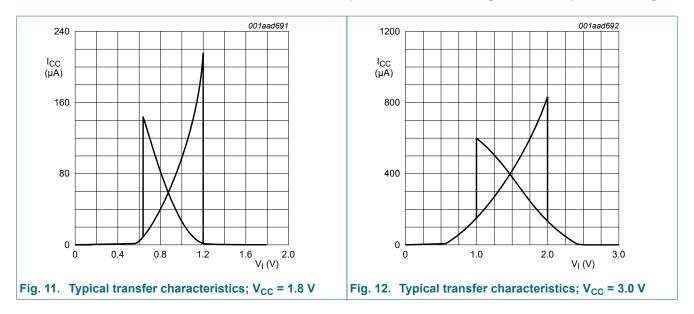
Voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 14.

| Symbol         | Parameter          | Parameter Conditions 25 °C  |      | 25 °C |      | _    | °C to<br>5 °C | -40 °C to<br>+125 °C |      | Unit |
|----------------|--------------------|---|------|-------|------|------|---------------|----------------------|------|------|
|                |                    |   | Min  | Тур   | Max  | Min  | Max           | Min                  | Max  |      |
| $V_{T+}$       | positive-going     | see Fig. 9 and Fig. 10  |      |       |      |      |               |                      |      |      |
|                | threshold voltage  | V <sub>CC</sub> = 0.8 V   | 0.30 | -     | 0.60 | 0.30 | 0.60          | 0.30                 | 0.62 | V    |
|                |                    | V <sub>CC</sub> = 1.1 V   | 0.53 | -     | 0.90 | 0.53 | 0.90          | 0.53                 | 0.92 | V    |
|                |                    | V <sub>CC</sub> = 1.4 V   | 0.74 | -     | 1.11 | 0.74 | 1.11          | 0.74                 | 1.13 | V    |
|                |                    | V <sub>CC</sub> = 1.65 V  | 0.91 | -     | 1.29 | 0.91 | 1.29          | 0.91                 | 1.31 | V    |
|                |                    | V <sub>CC</sub> = 2.3 V   | 1.37 | -     | 1.77 | 1.37 | 1.77          | 1.37                 | 1.80 | V    |
|                |                    | V <sub>CC</sub> = 3.0 V   | 1.88 | -     | 2.29 | 1.88 | 2.29          | 1.88                 | 2.32 | V    |
| $V_{T-}$       | negative-going     | see Fig. 9 and Fig. 10  |      |       |      |      |               |                      |      |      |
|                | threshold voltage  | V <sub>CC</sub> = 0.8 V   | 0.10 | -     | 0.60 | 0.10 | 0.60          | 0.10                 | 0.60 | V    |
|                |                    | V <sub>CC</sub> = 1.1 V   | 0.26 | -     | 0.65 | 0.26 | 0.65          | 0.26                 | 0.65 | V    |
|                |                    | V <sub>CC</sub> = 1.4 V   | 0.39 | -     | 0.75 | 0.39 | 0.75          | 0.39                 | 0.75 | V    |
|                |                    | V <sub>CC</sub> = 1.65 V  | 0.47 | -     | 0.84 | 0.47 | 0.84          | 0.47                 | 0.84 | V    |
|                |                    | V <sub>CC</sub> = 2.3 V   | 0.69 | -     | 1.04 | 0.69 | 1.04          | 0.69                 | 1.04 | V    |
|                |                    | V <sub>CC</sub> = 3.0 V   | 0.88 | -     | 1.24 | 0.88 | 1.24          | 0.88                 | 1.24 | V    |
| V <sub>H</sub> | hysteresis voltage | (V <sub>T+</sub> - V <sub>T-</sub> ); see <u>Fig. 9</u> ,<br><u>Fig. 10</u> , <u>Fig. 11</u> and <u>Fig. 12</u> |      |       |      |      |               |                      |      |      |
|                |                    | V <sub>CC</sub> = 0.8 V   | 0.07 | -     | 0.50 | 0.07 | 0.50          | 0.07                 | 0.50 | V    |
|                |                    | V <sub>CC</sub> = 1.1 V   | 0.08 | -     | 0.46 | 0.08 | 0.46          | 0.08                 | 0.46 | V    |
|                |                    | V <sub>CC</sub> = 1.4 V   | 0.18 | -     | 0.56 | 0.18 | 0.56          | 0.18                 | 0.56 | V    |
|                |                    | V <sub>CC</sub> = 1.65 V  | 0.27 | -     | 0.66 | 0.27 | 0.66          | 0.27                 | 0.66 | V    |
|                |                    | V <sub>CC</sub> = 2.3 V   | 0.53 | -     | 0.92 | 0.53 | 0.92          | 0.53                 | 0.92 | V    |
|                |                    | V <sub>CC</sub> = 3.0 V   | 0.79 | -     | 1.31 | 0.79 | 1.31          | 0.79                 | 1.31 | V    |

#### 10.2. Waveforms transfer characteristics



#### Low-power dual PCB configurable multiple function gate



## 11. Dynamic characteristics

#### **Table 10. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 14.

| Symbol Parameter    |             | Conditions                         |     | 25 °C   |      |     | °C to<br>5 °C | -40 °C to<br>+125 °C |      | Unit |
|---------------------|-------------|------------------------------------|-----|---------|------|-----|---------------|----------------------|------|------|
|                     |             |                                    | Min | Typ [1] | Max  | Min | Max           | Min                  | Max  |      |
| $C_L = 5 p$         | F           |                                    |     |         |      |     |               |                      |      |      |
| t <sub>pd</sub>     | propagation | nA, nB, nC to nY; see Fig. 13 [2]  |     |         |      |     |               |                      |      |      |
|                     | delay       | V <sub>CC</sub> = 0.8 V            | -   | 23.0    | -    | -   | -             | -                    | -    | ns   |
|                     |             | V <sub>CC</sub> = 1.1 V to 1.3 V   | 2.8 | 6.6     | 12.6 | 2.5 | 13.0          | 2.5                  | 13.2 | ns   |
|                     |             | V <sub>CC</sub> = 1.4 V to 1.6 V   | 2.3 | 4.7     | 7.6  | 2.5 | 8.2           | 2.5                  | 8.6  | ns   |
|                     |             | V <sub>CC</sub> = 1.65 V to 1.95 V | 2.2 | 3.9     | 6.2  | 2.0 | 6.8           | 2.0                  | 7.2  | ns   |
|                     |             | V <sub>CC</sub> = 2.3 V to 2.7 V   | 2.0 | 3.2     | 4.5  | 1.7 | 5.1           | 1.7                  | 5.3  | ns   |
|                     |             | V <sub>CC</sub> = 3.0 V to 3.6 V   | 1.9 | 2.8     | 3.9  | 1.5 | 4.1           | 1.5                  | 4.3  | ns   |
| C <sub>L</sub> = 10 | pF          |                                    |     |         |      |     |               |                      |      |      |
| t <sub>pd</sub>     | propagation | nA, nB, nC to nY; see Fig. 13 [2]  |     |         |      |     |               |                      |      |      |
|                     | delay       | V <sub>CC</sub> = 0.8 V            | -   | 26.6    | -    | -   | -             | -                    | -    | ns   |
|                     |             | V <sub>CC</sub> = 1.1 V to 1.3 V   | 3.2 | 7.4     | 14.3 | 2.9 | 14.9          | 2.9                  | 15.2 | ns   |
|                     |             | V <sub>CC</sub> = 1.4 V to 1.6 V   | 2.6 | 5.3     | 8.7  | 2.8 | 9.4           | 2.8                  | 9.8  | ns   |
|                     |             | V <sub>CC</sub> = 1.65 V to 1.95 V | 2.5 | 4.5     | 7.0  | 2.3 | 7.8           | 2.3                  | 8.2  | ns   |
|                     |             | V <sub>CC</sub> = 2.3 V to 2.7 V   | 2.4 | 3.7     | 5.2  | 2.1 | 5.9           | 2.1                  | 6.1  | ns   |
|                     |             | V <sub>CC</sub> = 3.0 V to 3.6 V   | 2.3 | 3.4     | 4.6  | 1.9 | 4.9           | 1.9                  | 5.1  | ns   |

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| Symbol Parameter     |                          | Conditions   | 25 °C |         |      |     | °C to<br>5 °C | -40 °C to<br>+125 °C |      | Unit |
|----------------------|--------------------------|--|-------|---------|------|-----|---------------|----------------------|------|------|
|                      |                          |  | Min   | Typ [1] | Max  | Min | Max           | Min                  | Max  |      |
| C <sub>L</sub> = 15  | pF                       |  |       |         |      |     |               |                      |      |      |
| t <sub>pd</sub>      | propagation              | nA, nB, nC to nY; see Fig. 13 [2]                      |       |         |      |     |               |                      |      |      |
|                      | delay                    | V <sub>CC</sub> = 0.8 V                                | -     | 30.1    | -    | -   | -             | -                    | -    | ns   |
|                      |                          | V <sub>CC</sub> = 1.1 V to 1.3 V                       | 3.6   | 8.2     | 16.0 | 3.2 | 16.7          | 3.2                  | 17.0 | ns   |
|                      |                          | V <sub>CC</sub> = 1.4 V to 1.6 V                       | 2.9   | 5.9     | 9.6  | 3.1 | 10.4          | 3.1                  | 10.9 | ns   |
|                      |                          | V <sub>CC</sub> = 1.65 V to 1.95 V                     | 2.8   | 5.0     | 7.8  | 2.5 | 8.7           | 2.5                  | 9.1  | ns   |
|                      |                          | V <sub>CC</sub> = 2.3 V to 2.7 V                       | 2.7   | 4.2     | 5.8  | 2.4 | 6.5           | 2.4                  | 6.9  | ns   |
|                      |                          | V <sub>CC</sub> = 3.0 V to 3.6 V                       |       | 3.8     | 5.1  | 2.2 | 5.5           | 2.2                  | 5.7  | ns   |
| C <sub>L</sub> = 30  | pF                       |  |       |         |      |     |               |                      |      |      |
| t <sub>pd</sub>      | propagation              | nA, nB, nC to nY; see Fig. 13 [2]                      |       |         |      |     |               |                      |      |      |
|                      | delay                    | V <sub>CC</sub> = 0.8 V                                | -     | 38.3    | -    | -   | -             | -                    | -    | ns   |
|                      |                          | V <sub>CC</sub> = 1.1 V to 1.3 V                       | 4.6   | 10.5    | 20.9 | 4.0 | 21.8          | 4.0                  | 22.2 | ns   |
|                      |                          | V <sub>CC</sub> = 1.4 V to 1.6 V                       | 3.7   | 7.4     | 12.2 | 3.8 | 13.3          | 3.8                  | 14.0 | ns   |
|                      |                          | V <sub>CC</sub> = 1.65 V to 1.95 V                     | 3.5   | 6.3     | 9.9  | 3.2 | 11.1          | 3.2                  | 11.8 | ns   |
|                      |                          | V <sub>CC</sub> = 2.3 V to 2.7 V                       | 3.4   | 5.3     | 7.4  | 3.1 | 8.3           | 3.1                  | 8.8  | ns   |
|                      |                          | V <sub>CC</sub> = 3.0 V to 3.6 V                       | 3.2   | 4.9     | 6.6  | 2.8 | 7.0           | 2.8                  | 7.4  | ns   |
| C <sub>L</sub> = 5 p | F, 10 pF, 15 pl          | F and 30 pF  |       |         |      |     | •             |                      |      |      |
| C <sub>PD</sub>      | power                    | $f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3] |       |         |      |     |               |                      |      |      |
|                      | dissipation capacitance  | V <sub>CC</sub> = 0.8 V                                | -     | 2.6     | -    | -   | -             | -                    | -    | pF   |
|                      | oapaoita 10 <del>0</del> | V <sub>CC</sub> = 1.1 V to 1.3 V                       | -     | 2.8     | -    | -   | -             | -                    | -    | рF   |
|                      |                          | V <sub>CC</sub> = 1.4 V to 1.6 V                       | -     | 2.9     | -    | -   | -             | -                    | -    | pF   |
|                      |                          | V <sub>CC</sub> = 1.65 V to 1.95 V                     | -     | 3.1     | -    | -   | -             | -                    | -    | pF   |
|                      |                          | V <sub>CC</sub> = 2.3 V to 2.7 V                       | -     | 3.7     | -    | -   | -             | -                    | -    | pF   |
|                      |                          | V <sub>CC</sub> = 3.0 V to 3.6 V                       | -     | 4.3     | -    | -   | -             | -                    | -    | pF   |

- All typical values are measured at nominal V<sub>CC</sub>.
- $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$   $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

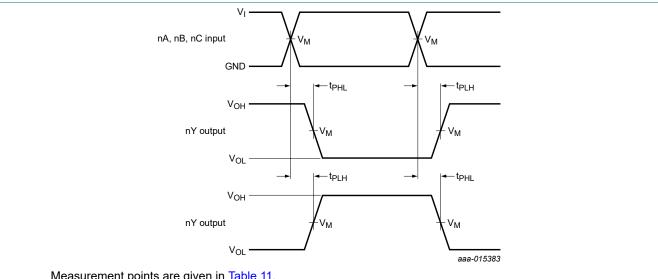
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;  $\Sigma (C_L \times V_{CC}^{\ 2} \times f_o) = \text{sum of the outputs}.$ 

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#### 11.1. Waveforms and test circuit



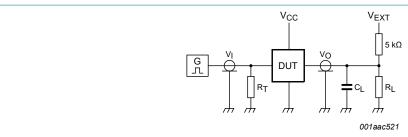
Measurement points are given in Table 11.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage levels that occur with the output load.

Fig. 13. Input nA, nB and nC to output nY propagation delay times

**Table 11. Measurement points** 

| Supply voltage  | Output                | Input                 |                 |             |  |  |  |  |
|-----------------|-----------------------|-----------------------|-----------------|-------------|--|--|--|--|
| V <sub>CC</sub> | V <sub>M</sub>        | V <sub>M</sub>        | VI              | $t_r = t_f$ |  |  |  |  |
| 0.8 V to 3.6 V  | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> | V <sub>CC</sub> | ≤ 3.0 ns    |  |  |  |  |



Test data is given in Table 12.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig. 14. Test circuit for measuring switching times

Table 12. Test data

| Supply voltage  | Load                         |                              | V <sub>EXT</sub>                    |                                     |                                     |  |
|-----------------|------------------------------|------------------------------|-------------------------------------|-------------------------------------|-------------------------------------|--|
| V <sub>CC</sub> | CL                           | R <sub>L</sub> [1]           | t <sub>PLH</sub> , t <sub>PHL</sub> | t <sub>PZH</sub> , t <sub>PHZ</sub> | t <sub>PZL</sub> , t <sub>PLZ</sub> |  |
| 0.8 V to 3.6 V  | 5 pF, 10 pF, 15 pF and 30 pF | 5 k $\Omega$ or 1 M $\Omega$ | open                                | GND                                 | 2V <sub>CC</sub>                    |  |

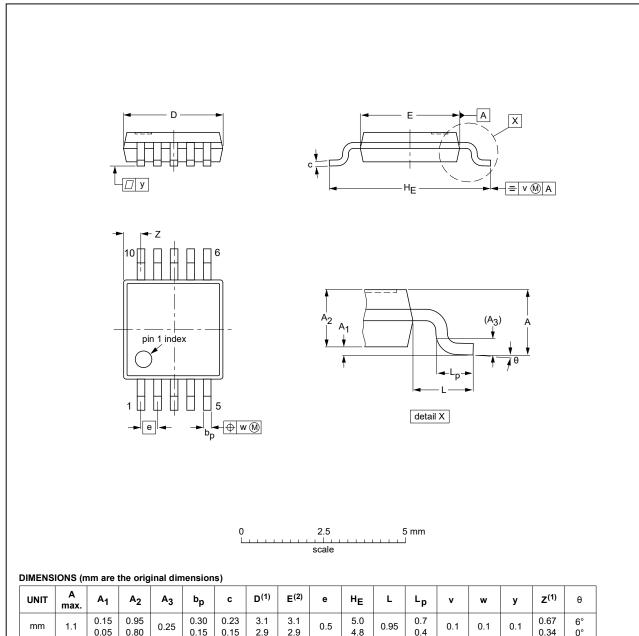
For measuring enable and disable times,  $R_L = 5 \text{ k}\Omega$ . For measuring propagation delays, setup and hold times and pulse width  $R_{L}$  = 1  $M\Omega.\,$ 

#### Low-power dual PCB configurable multiple function gate

## 12. Package outline

#### TSSOP10: plastic thin shrink small outline package; 10 leads; body width 3 mm

SOT552-1



| UNIT | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | А3   | bp           | С            | D <sup>(1)</sup> | E <sup>(2)</sup> | е   | HE         | L    | Lp         | v   | w   | у   | Z <sup>(1)</sup> | θ        |
|------|-----------|----------------|----------------|------|--------------|--------------|------------------|------------------|-----|------------|------|------------|-----|-----|-----|------------------|----------|
| mm   | 1.1       | 0.15<br>0.05   | 0.95<br>0.80   | 0.25 | 0.30<br>0.15 | 0.23<br>0.15 | 3.1<br>2.9       | 3.1<br>2.9       | 0.5 | 5.0<br>4.8 | 0.95 | 0.7<br>0.4 | 0.1 | 0.1 | 0.1 | 0.67<br>0.34     | 6°<br>0° |

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE  |     | REFER | EUROPEAN | ISSUE DATE |            |                                 |  |
|----------|-----|-------|----------|------------|------------|---------------------------------|--|
| VERSION  | IEC | JEDEC | JEITA    |            | PROJECTION | ISSUE DATE                      |  |
| SOT552-1 |     |       |          |            |            | <del>99-07-29</del><br>03-02-18 |  |

Fig. 15. Package outline SOT552-1 (TSSOP10)

#### Low-power dual PCB configurable multiple function gate

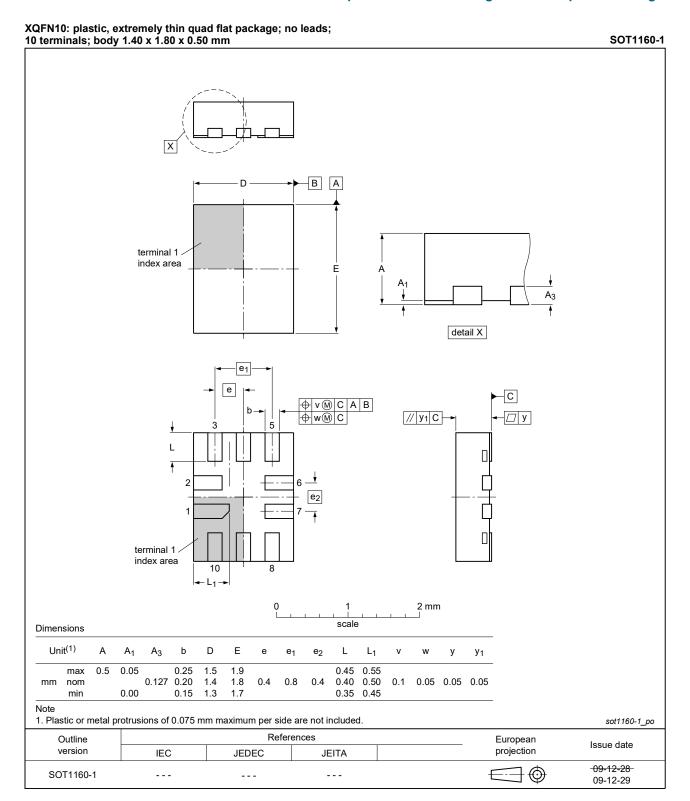


Fig. 16. Package outline SOT1160-1 (XQFN10)

Nexperia

**74AUP2G97** 

#### Low-power dual PCB configurable multiple function gate

## 13. Abbreviations

#### **Table 13. Abbreviations**

| Acronym | Description             |
|---------|-------------------------|
| CDM     | Charged Device Model    |
| DUT     | Device Under Test       |
| ESD     | ElectroStatic Discharge |
| НВМ     | Human Body Model        |
| PCB     | Printed-Circuit Board   |

## 14. Revision history

#### **Table 14. Revision history**

| Document ID    | Release date  | Data sheet status  | Change notice | Supersedes    |  |  |  |  |  |
|----------------|---|--------------------|---------------|---------------|--|--|--|--|--|
| 74AUP2G97 v.4  | 20230801  | Product data sheet | -             | 74AUP2G97 v.3 |  |  |  |  |  |
| Modifications: | <u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.  |                    |               |               |  |  |  |  |  |
| 74AUP2G97 v.3  | 20190722 Product data sheet - 74AUP2G97 v.2   |                    |               |               |  |  |  |  |  |
| Modifications: | <ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type number 74AUP2G97GF (SOT1081-2) removed.</li> </ul> |                    |               |               |  |  |  |  |  |
| 74AUP2G97 v.2  | 20151202  | Product data sheet | -             | 74AUP2G97 v.1 |  |  |  |  |  |
| Modifications: | <ul> <li>Maximum value temperature range TSSOP10 (74AUP2G97DP) changed from 85 °C to 125 °C.</li> <li>Removed 74AUP2G97GM (SOT1049-3).</li> </ul>   |                    |               |               |  |  |  |  |  |
| 74AUP2G97 v.1  | 20141104  | Product data sheet | -             | -             |  |  |  |  |  |

#### Low-power dual PCB configurable multiple function gate

#### 15. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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#### Low-power dual PCB configurable multiple function gate

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